Medium power transistor (–60V, –2A)

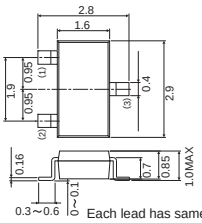
2SA2094

●Features

1) High speed switching.
   (Tf : Typ. : 30ns at I_C = −2A)
2) Low saturation voltage, typically
   (Typ. : −200mV at I_C = −1A, I_B = −0.1A)
3) Strong discharge power for inductive load and capacitance load.
4) Complements the 2SC5866

●Dimensions (Unit : mm)

TSMT3



(1) Base
(2) Emitter
(3) Collector

Each lead has same dimensions

Abbreviated symbol : VP

●Applications

Low frequency amplifier
High speed switching

●Structure

PNP epitaxial planar silicon transistor

●Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
2SA2094		◯

●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		V_{CBO}	–60	V	
Collector-emitter voltage		V_{CEO}	–60	V	
Emitter-base voltage		V_{EBO}	–6	V	
Collector current	DC	I_C	–2	A	
	Pulsed	I_{CP}	–4	A	∗1
Power dissipation		P_C	500	mW	∗2
Junction temperature		Tj	150	°C	
Range of storage temperature		Tstg	–55 to 150	°C	

∗1 Pw=10ms
∗2 Each terminal mounted on a recommended land

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	BV_{CEO}	–60	–	–	V	I_C= –1mA
Collector-base breakdown voltage	BV_{CBO}	–60	–	–	V	I_C= –100μA
Emitter-base breakdown voltage	BV_{EBO}	–6	–	–	V	I_E= –100μA
Collector cut-off current	I_{CBO}	–	–	–1.0	μA	V_{CB}= –40V
Emitter cut-off current	I_{EBO}	–	–	–1.0	μA	V_{EB}= –4V
Collector-emitter saturation voltage	$V_{CE\ (sat)}$	–	–200	–500	mV	I_C= –1A, I_B= –0.1A *1
DC current gain	h_{FE}	120	–	270	–	V_{CE}= –2V, I_C= –100mA *1
Transition frequency	f_T	–	300	–	MHz	V_{CE}= –10V, I_E=100mA, f=10MHz *1
Corrector output capacitance	Cob	–	25	–	pF	V_{CB}= –10V, I_E=0mA, f=1MHz
Turn-on time	Ton	–	25	–	ns	I_C= –2A, I_{B1}= –200mA, I_{B2}=200mA, V_{CC}≒25V *2
Storage time	Tstg	–	100	–	ns	
Fall time	Tf	–	30	–	ns	

*1 Non repetitive pulse
*2 See Switching charactaristics measurement circuits

●h_{FE} RANK

Q
120–270

●Electrical characteristic curves

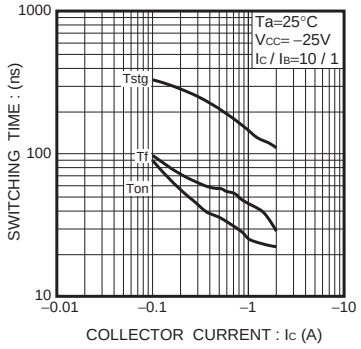


Fig.1 Switching Time

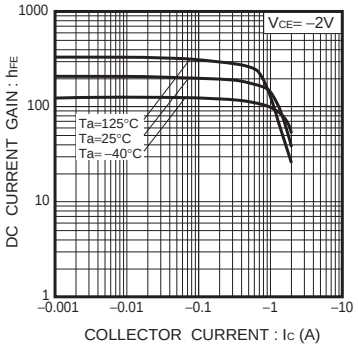


Fig.2 DC Current Gain vs. Collector Current (I)

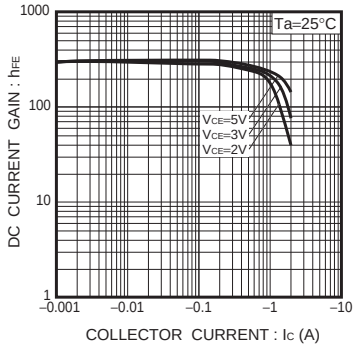


Fig.3 DC Current Gain vs. Collector Current (II)

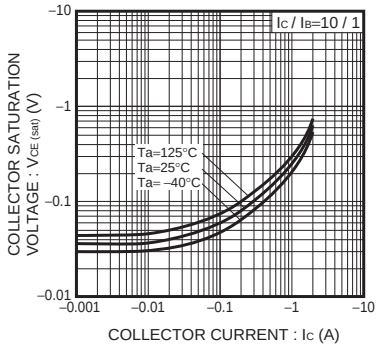


Fig.4 Collector-Emitter Saturation Voltage vs. Collector Current (I)

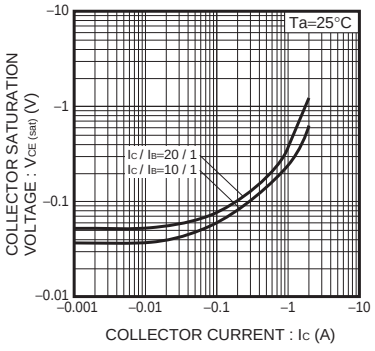


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II)

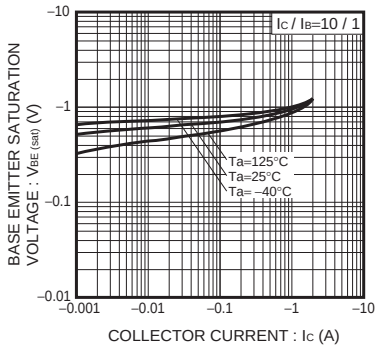


Fig.6 Base-Emitter Saturation Voltage vs. Collecter Current

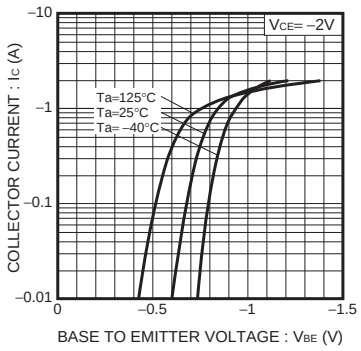


Fig.7 Grounded Emitter Propagation Characteristics

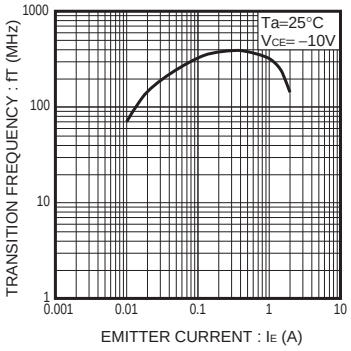


Fig.8 Transition Frequency

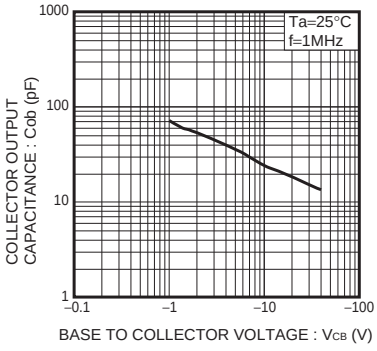
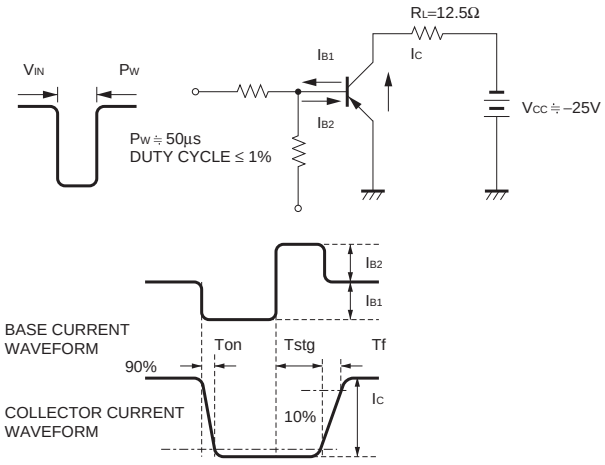


Fig.9 Collector Output Capacitance

●Switching characteristics measurement circuits



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